

09583530-060100

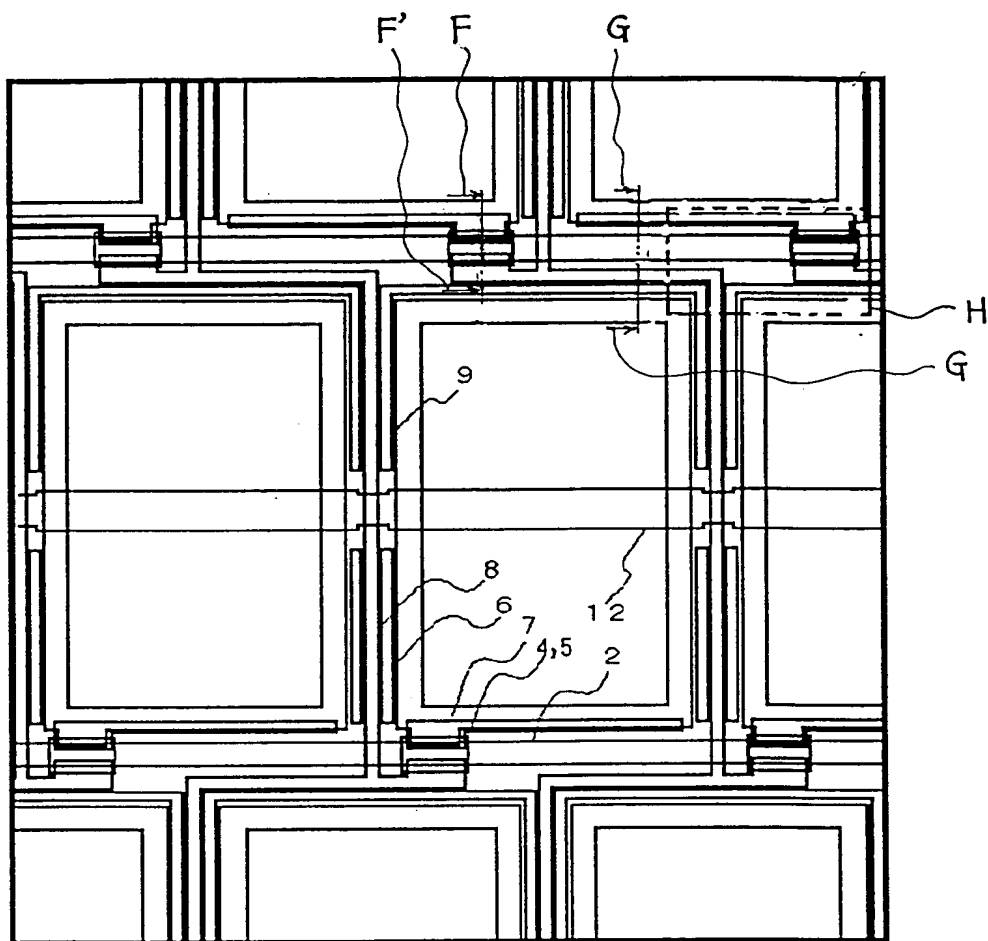


Fig. 1
PRIOR ART

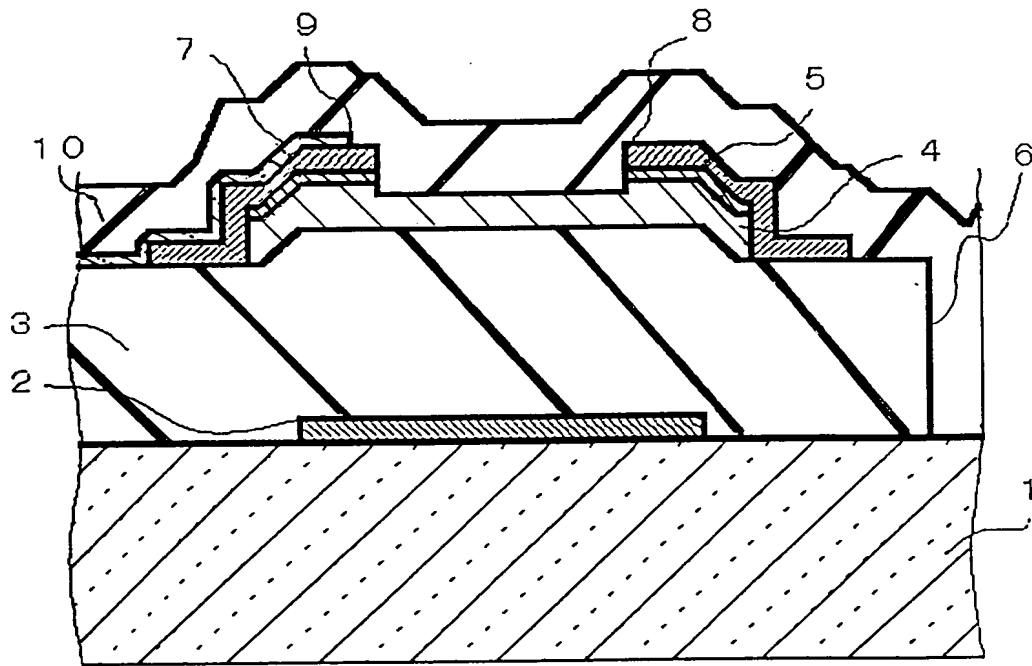


Fig. 2
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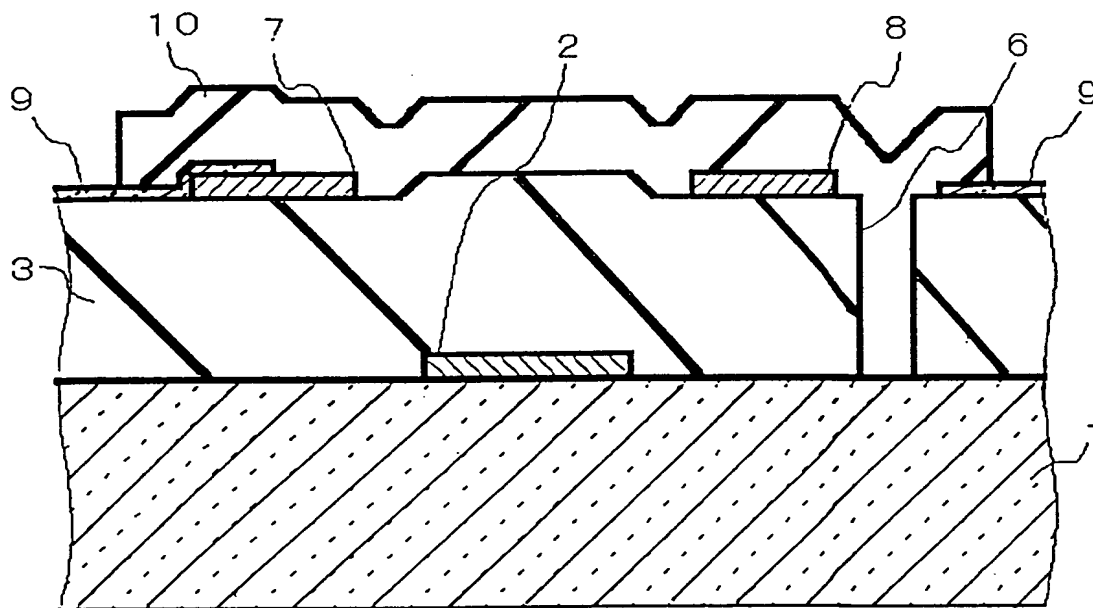


Fig. 3
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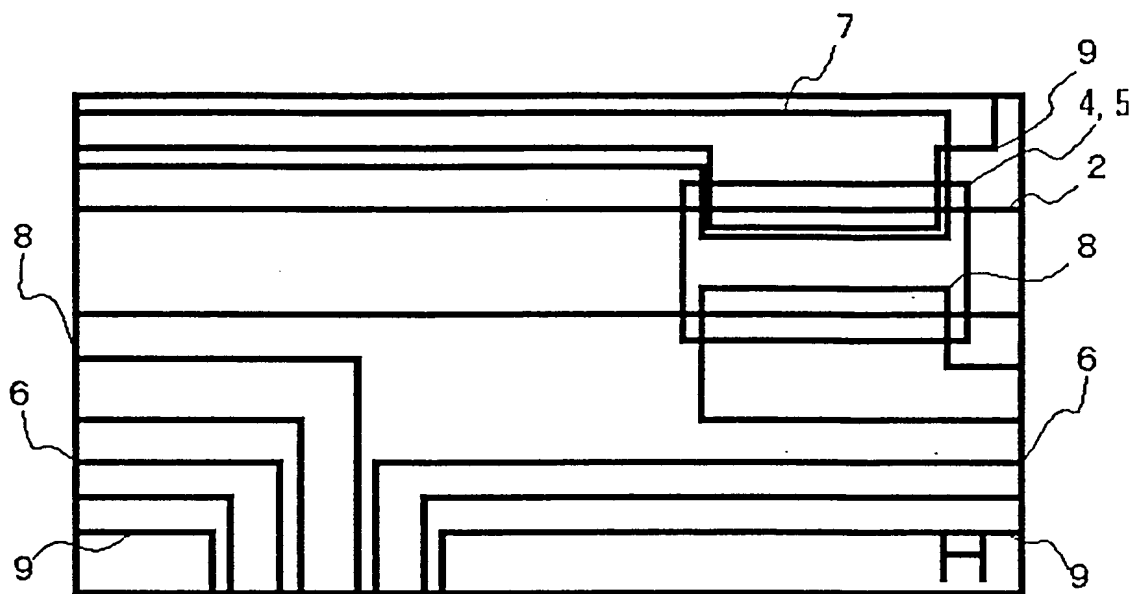


Fig. 4
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007090-06523560

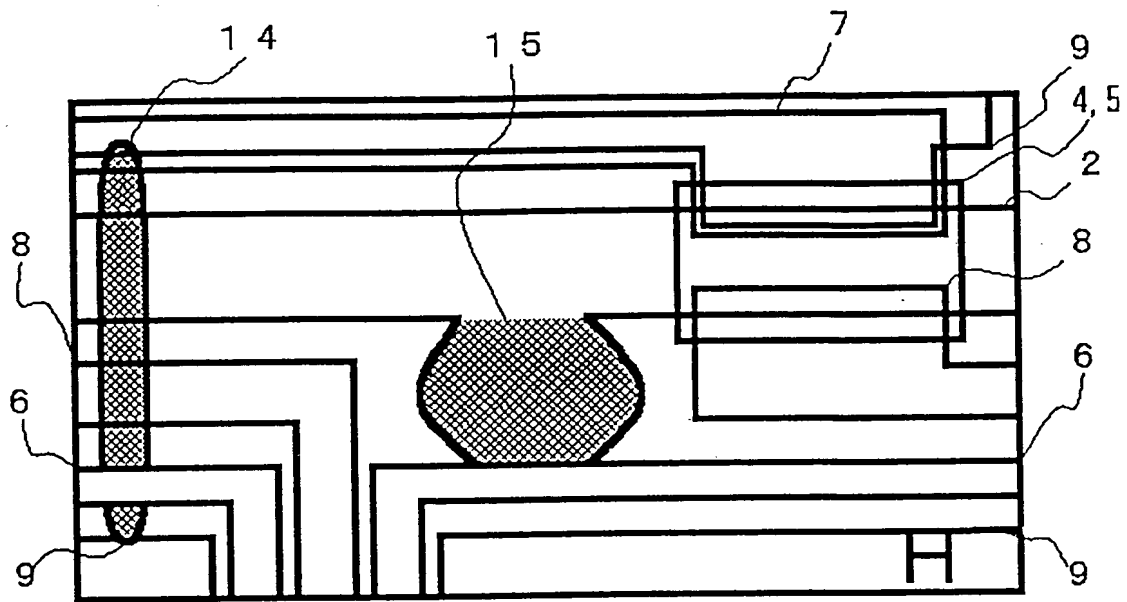


Fig. 5
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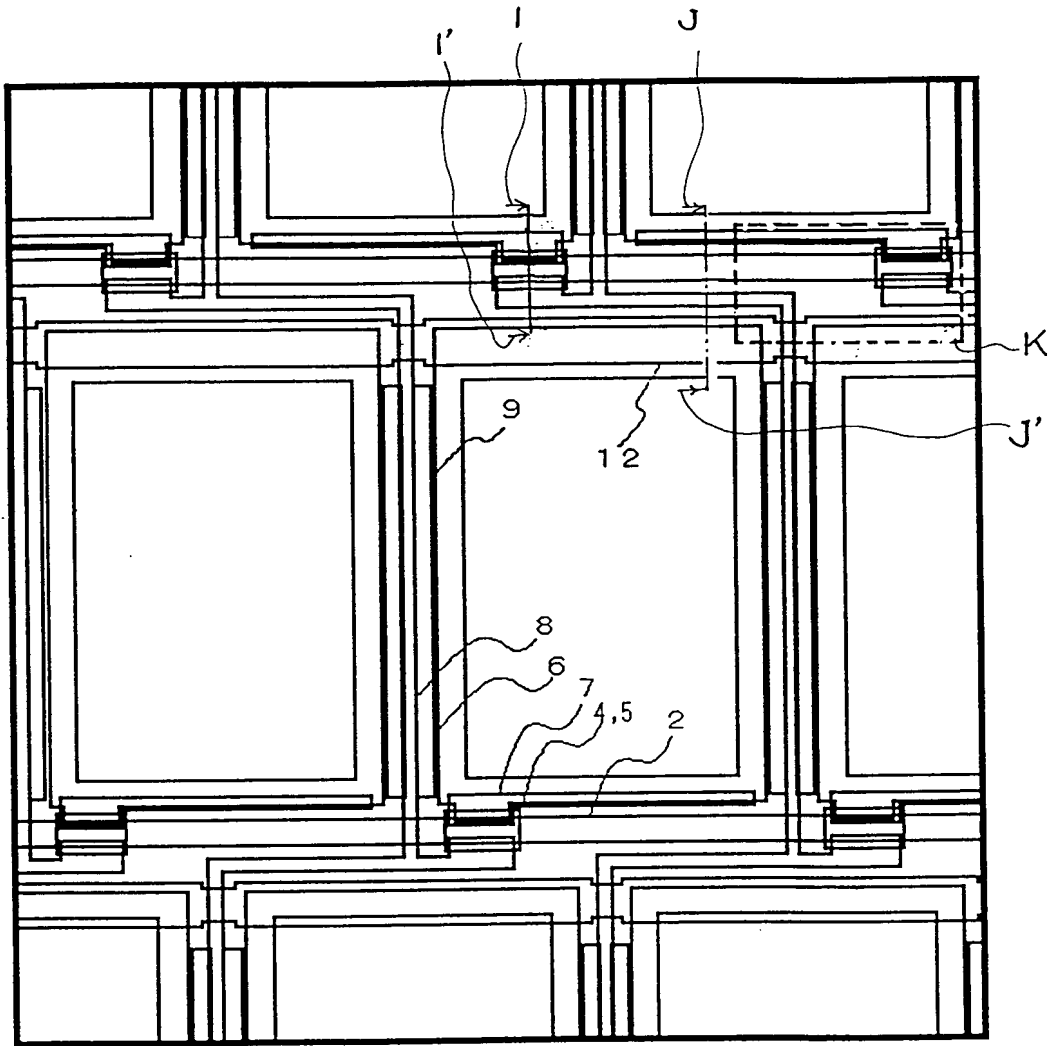


Fig. 6
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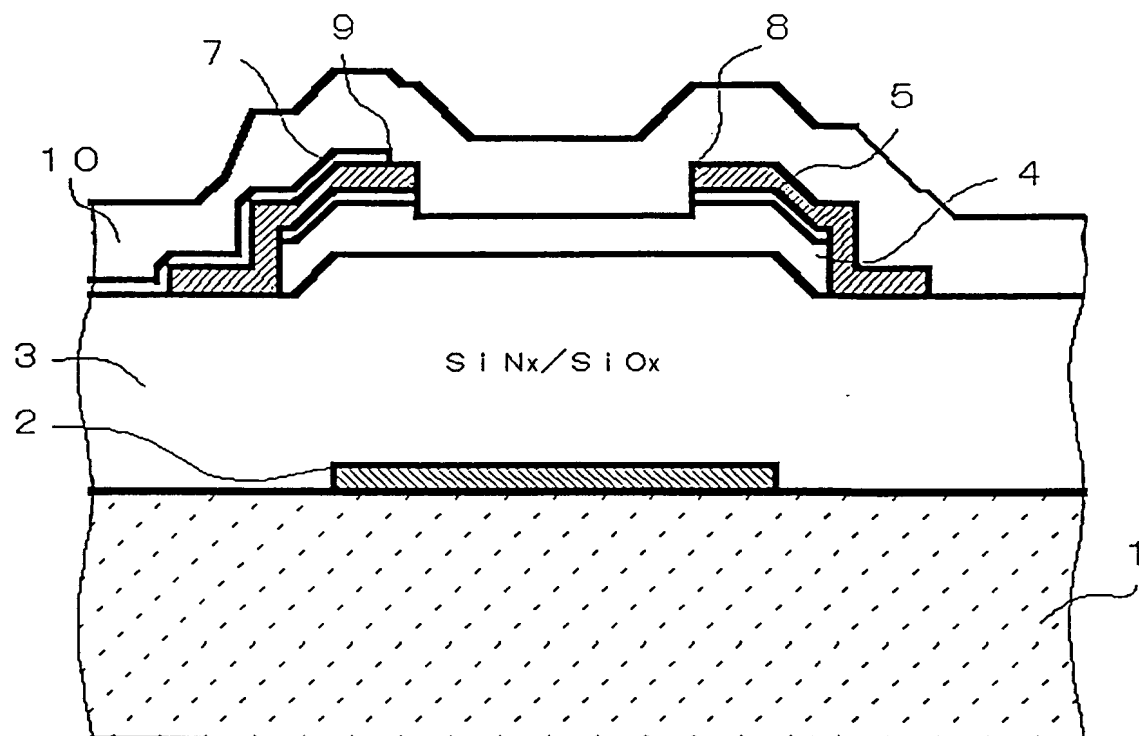


Fig. 7
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095330-050100

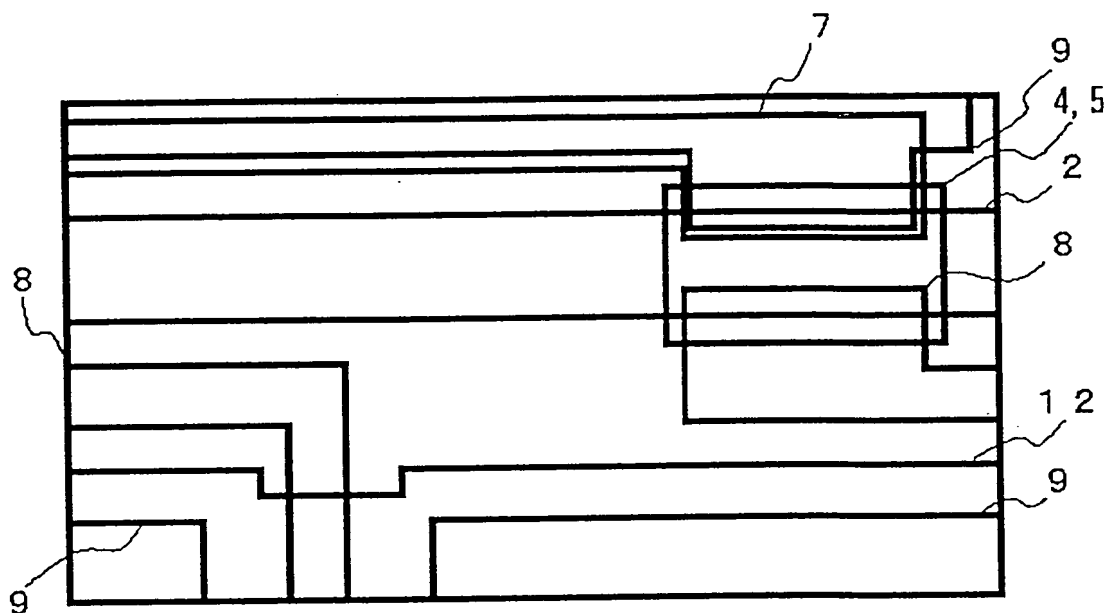


Fig. 9
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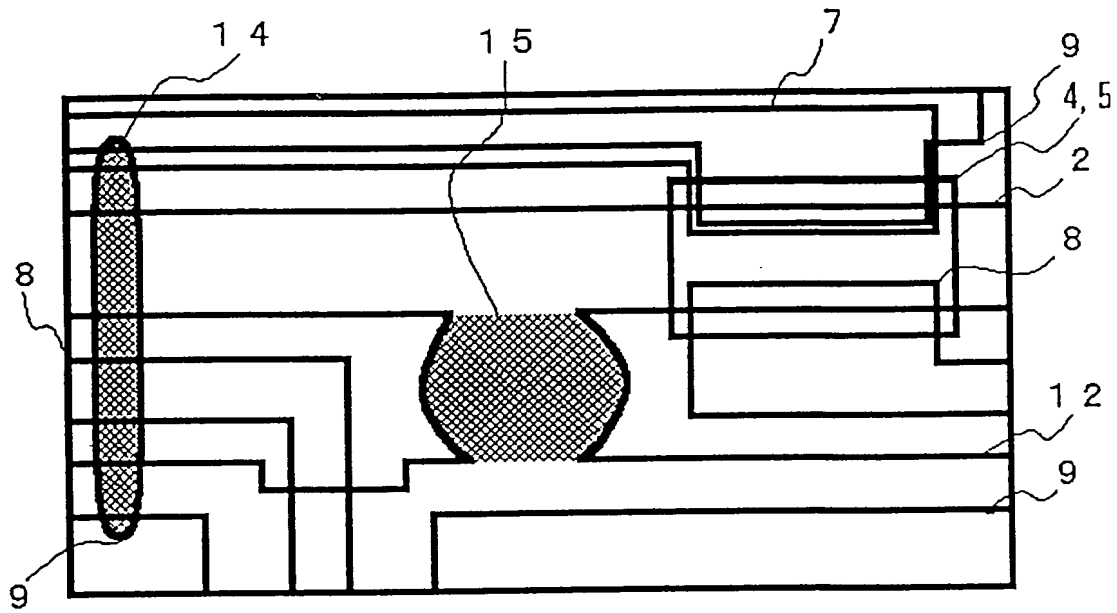


Fig. 10
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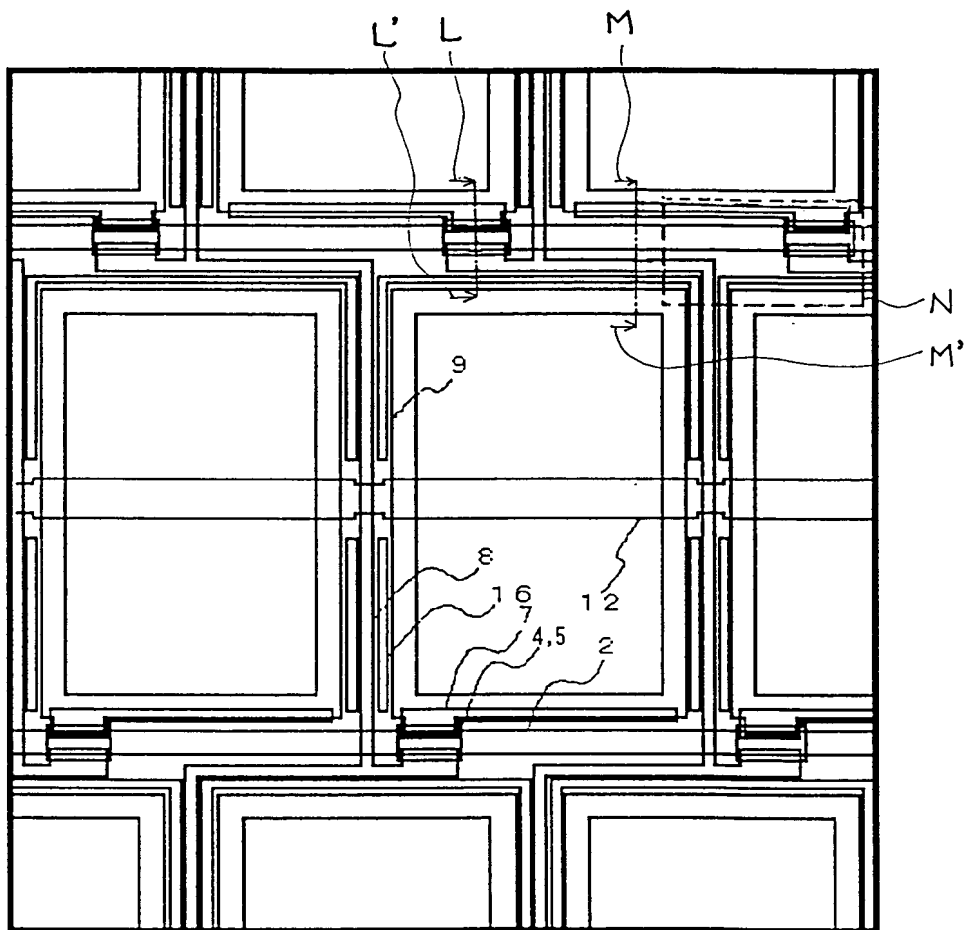


Fig. 11
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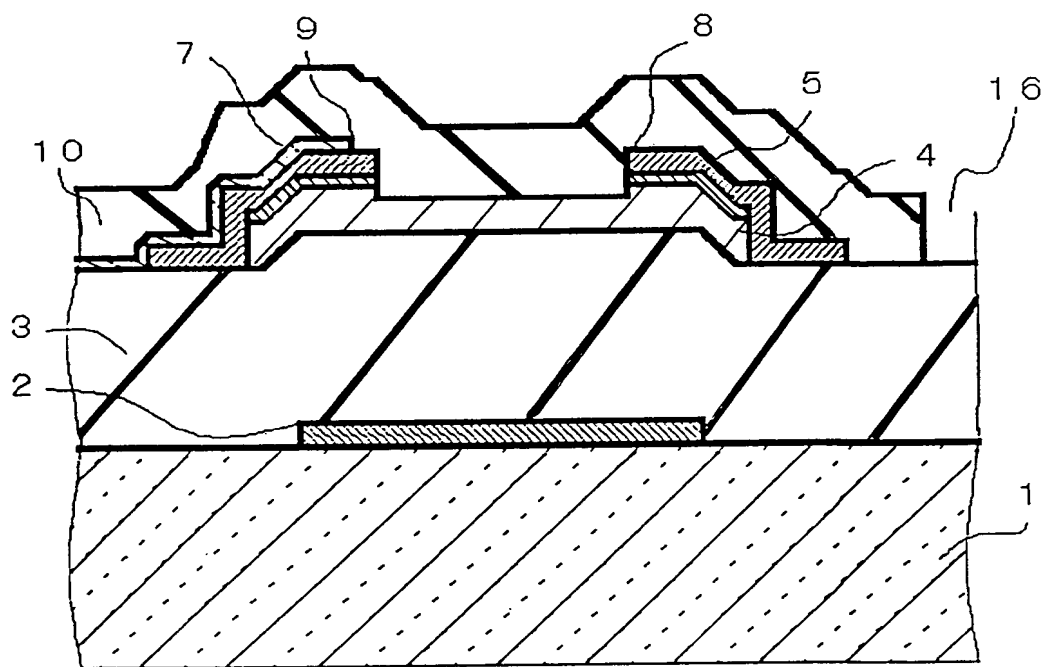


Fig. 12
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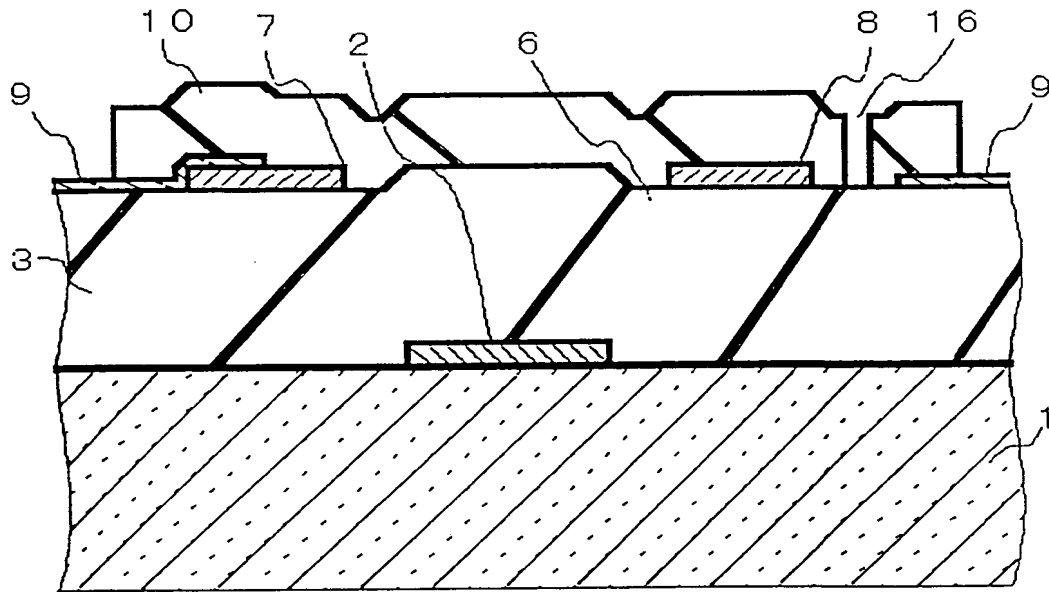


Fig. 13
PRIOR ART

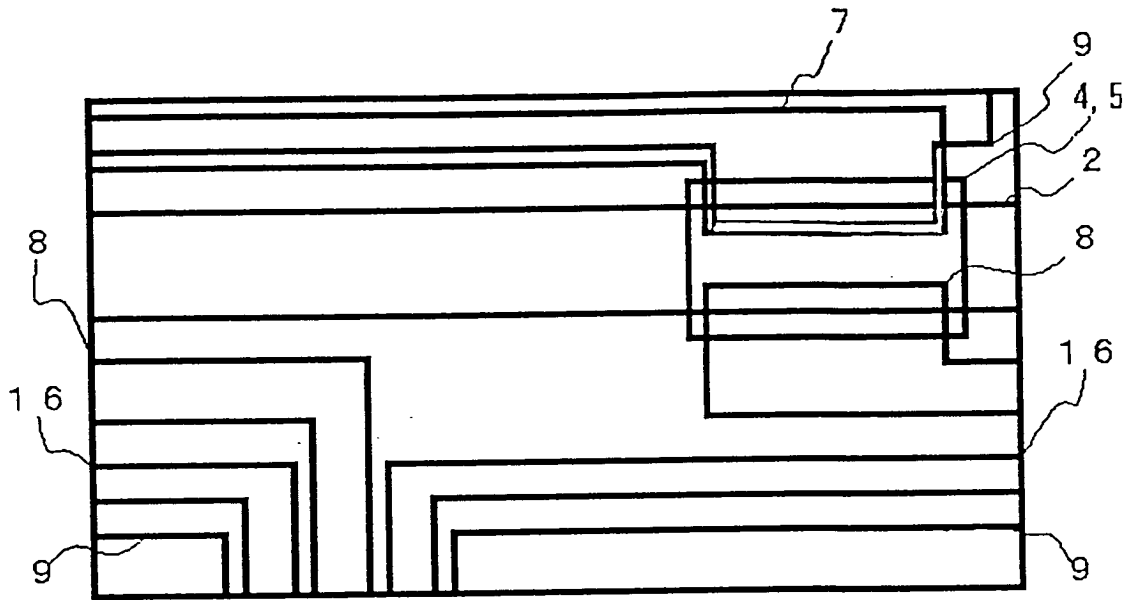


Fig. 14
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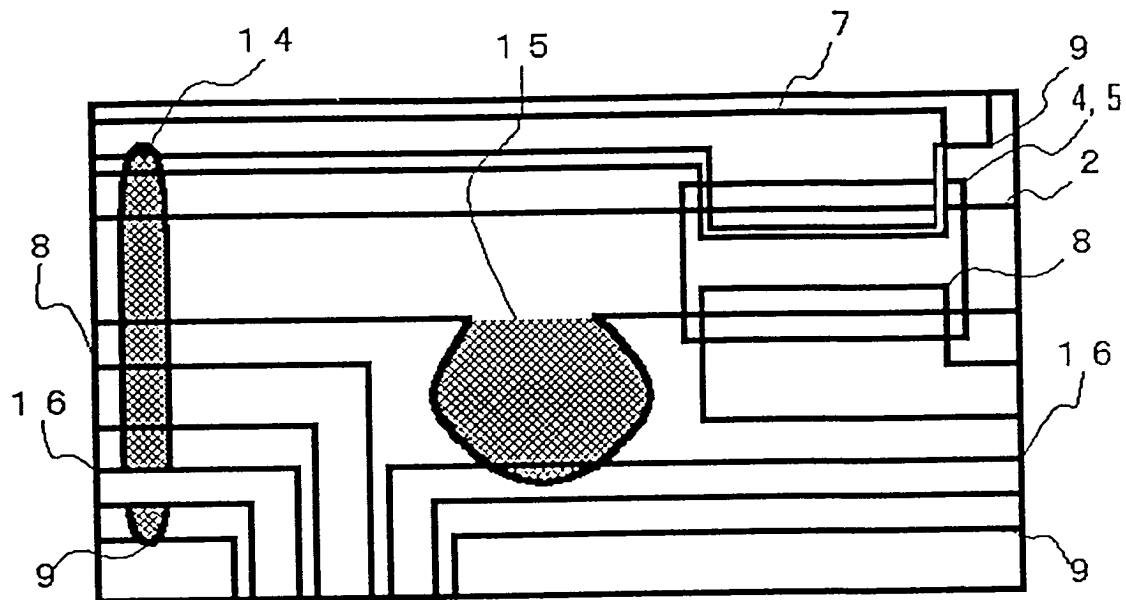


Fig. 15
PRIOR ART

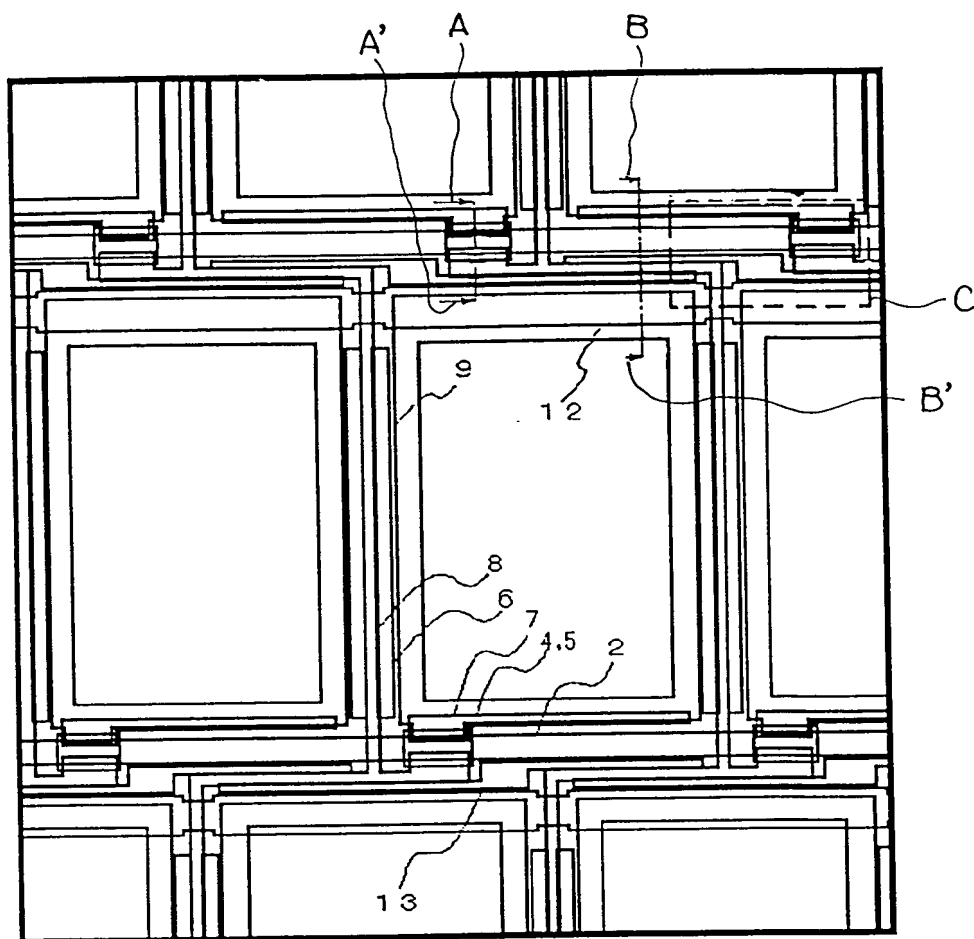


Fig. 16

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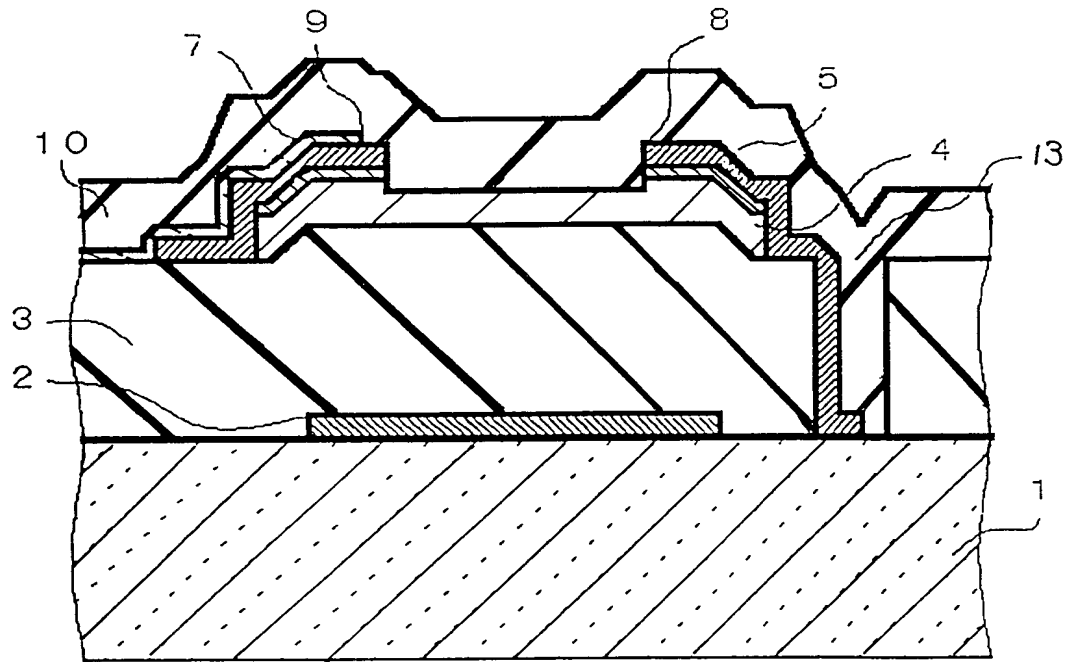


Fig. 17

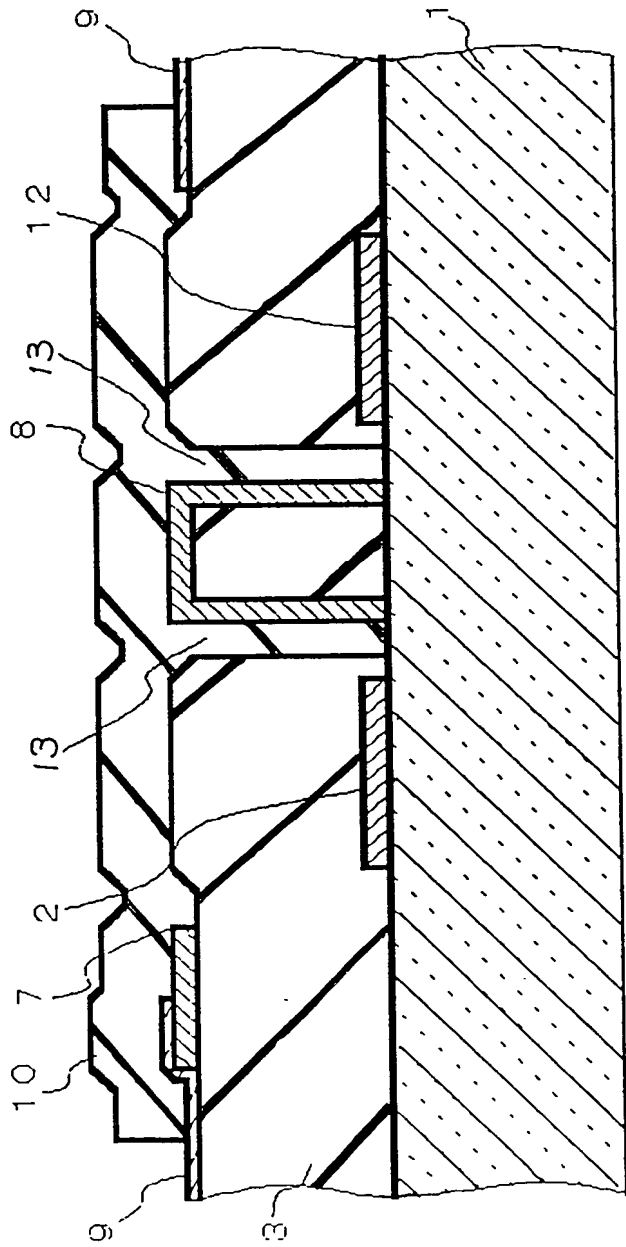


Fig. 18

This diagram shows a cross-sectional view of a multi-layered structure. The structure consists of several horizontal layers and internal components. Key features include:

- Layer 1:** The bottom-most layer, which is divided into sections by vertical lines.
- Layer 2:** A layer above Layer 1, containing a cross-hatched region on the left and a solid region on the right.
- Layer 3:** A thin layer above Layer 2, also containing a cross-hatched region on the left and a solid region on the right.
- Layer 4:** A layer above Layer 3, containing a cross-hatched region on the left and a solid region on the right.
- Layer 5:** A layer above Layer 4, containing a cross-hatched region on the left and a solid region on the right.
- Layer 6:** A layer above Layer 5, containing a cross-hatched region on the left and a solid region on the right.
- Layer 7:** A layer above Layer 6, containing a cross-hatched region on the left and a solid region on the right.
- Layer 8:** A layer above Layer 7, containing a cross-hatched region on the left and a solid region on the right.
- Layer 9:** The top-most layer, which is divided into sections by vertical lines.

Labels 1 through 9 are used to identify specific components or layers within the structure. The cross-hatched regions likely represent a specific material or a specific state of the material.

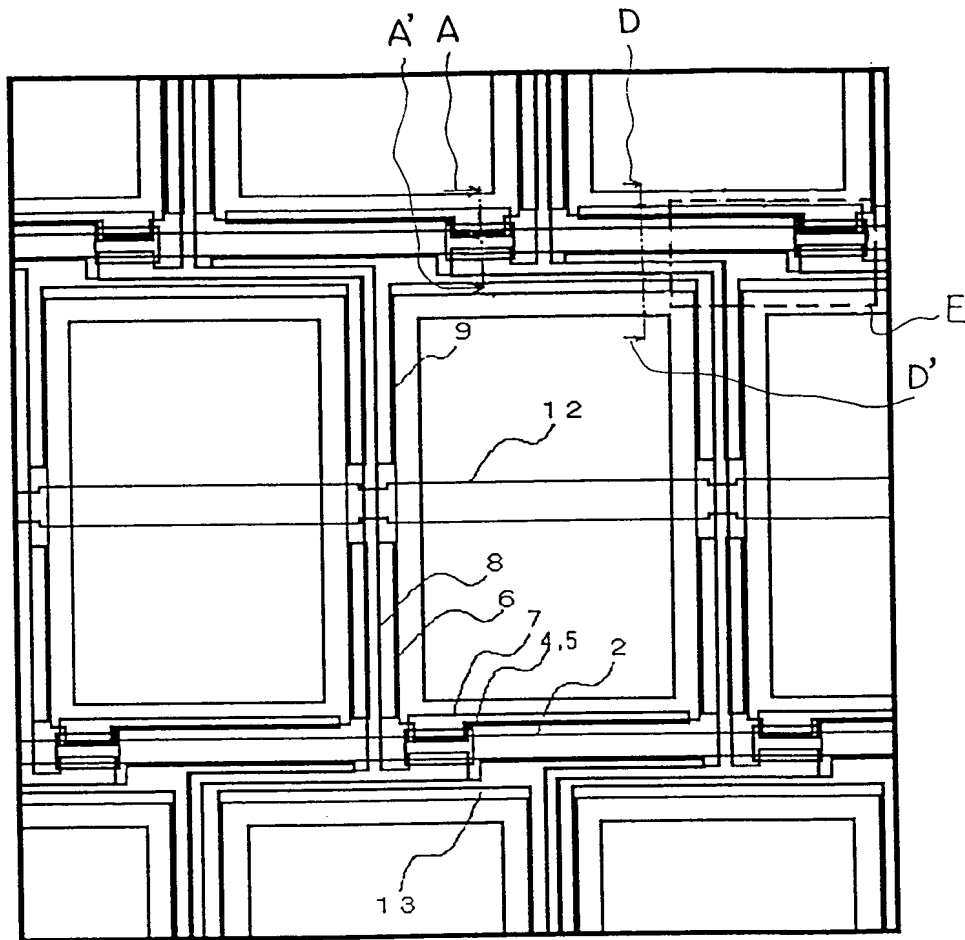


Fig. 21

A cross-sectional view of a semiconductor device. A substrate 1 is shown at the bottom, indicated by diagonal hatching. A layer 2 is formed on the substrate. A sawtooth-shaped pattern 3 is formed on layer 2. A layer 4 is formed on the top surface of the sawtooth pattern 3. A layer 5 is formed on the side surface of the sawtooth pattern 3. A layer 6 is formed on the top surface of the sawtooth pattern 3. A layer 7 is formed on the side surface of the sawtooth pattern 3. A layer 8 is formed on the top surface of the sawtooth pattern 3. A layer 9 is formed on the side surface of the sawtooth pattern 3. A layer 10 is formed on the top surface of the sawtooth pattern 3.

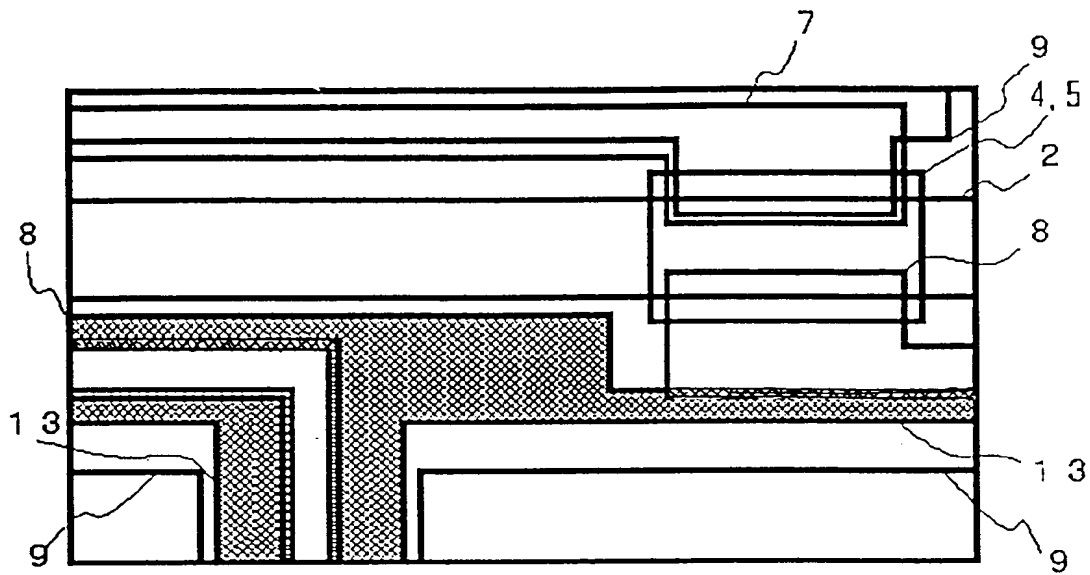


Fig. 23